NSN 5961-00-764-0018

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-764-0018 **Inclosure Material:** Ceramic **Overall Length:** 0.060 inches **Overall Diameter:** 0.120 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** -20.0 breakover voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 100.0 milliwatts small-signal input power, common-collector preset **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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